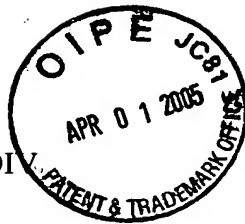


DOCKET NO: 245469US-2 DIV 1



IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :  
TADASHI IGUCHI, ET AL. : EXAMINER: CHEN, J. S. J.  
SERIAL NO: 10/716,556 :  
FILED: NOVEMBER 20, 2003 : GROUP ART UNIT: 2813  
FOR: NONVOLATILE :  
SEMICONDUCTOR MEMORY DEVICE  
AND ITS MANUFACTURING METHOD

AMENDMENT

COMMISSIONER FOR PATENTS  
ALEXANDRIA, VIRGINIA 22313

SIR:

In response to the Office Action of January 11, 2005, please amend the above-identified application as follows:

**Amendments to the Specification** begin on page 2 of this paper.

**Amendments to the Claims** are reflected in the listing of claims which begins on page 3 of this paper.

**Remarks/Arguments** begin on page 6 of this paper.